



# CSD13383F4 12 V N-Channel FemtoFET™ MOSFET

## 1 Features

- Low On-Resistance
- Ultra Low  $Q_g$  and  $Q_{gd}$
- Ultra-Small Footprint (0402 Case Size)
  - 1.0 mm × 0.6 mm
- Low Profile
  - 0.35 mm Height
- Integrated ESD Protection Diode
  - Rated >2 kV HBM
  - Rated >2 kV CDM
- Lead and Halogen Free
- RoHS Compliant

## 2 Applications

- Optimized for Load Switch Applications
- Optimized for General Purpose Switching Applications
- Single-Cell Battery Applications
- Handheld and Mobile Applications

## 3 Description

This 37 mΩ, 12 V N-channel FemtoFET™ MOSFET technology is designed and optimized to minimize the footprint in many handheld and mobile applications. This technology is capable of replacing standard small signal MOSFETs while providing at least a 60% reduction in footprint size.

### Product Summary

$T_A = 25^\circ\text{C}$		TYPICAL VALUE	UNIT
$V_{DS}$	Drain-to-Source Voltage	12	V
$Q_g$	Gate Charge Total (4.5 V)	2.0	nC
$Q_{gd}$	Gate Charge Gate-to-Drain	0.6	nC
$R_{DS(on)}$	Drain-to-Source On-Resistance	$V_{GS} = 2.5\text{ V}$	53
		$V_{GS} = 4.5\text{ V}$	37
$V_{GS(th)}$	Threshold Voltage	1.0	V

### Ordering Information<sup>(1)</sup>

DEVICE	QTY	MEDIA	PACKAGE	SHIP
CSD13383F4	3000	7-Inch Reel	Femto (0402) 1.0 mm × 0.6 mm SMD Lead Less	Tape and Reel
CSD13383F4T	250			

(1) For all available packages, see the orderable addendum at the end of the data sheet.

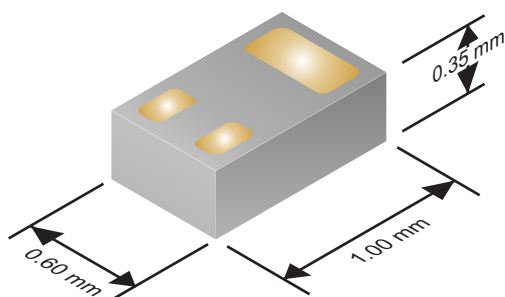
### Absolute Maximum Ratings

$T_A = 25^\circ\text{C}$		VALUE	UNIT
$V_{DS}$	Drain-to-Source Voltage	12	V
$V_{GS}$	Gate-to-Source Voltage	±10	V
$I_D$	Continuous Drain Current <sup>(1)</sup>	2.9	A
$I_{DM}$	Pulsed Drain Current <sup>(1)(2)</sup>	27	A
$I_G$	Continuous Gate Clamp Current	25	mA
	Pulsed Gate Clamp Current <sup>(1)(2)</sup>	250	
$P_D$	Power Dissipation	500	mW
ESD Rating	Human Body Model (HBM)	2	kV
	Charged Device Model (CDM)	2	kV
$T_J, T_{stg}$	Operating Junction Temperature Storage Temperature	–55 to 150	°C
$E_{AS}$	Avalanche Energy, single pulse $I_D = 6.7$ , $L = 0.1\text{ mH}$ , $R_G = 25\ \Omega$	2.2	mJ

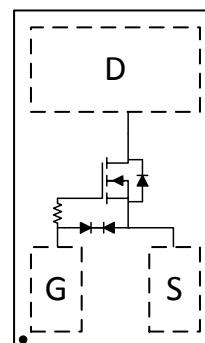
(1) Typical  $R_{\theta JA} = 250^\circ\text{C/W}$ .

(2) Pulse duration ≤ 100 μs, duty cycle ≤ 1%.

Typical Part Dimensions



Top View



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## 4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

<b>Changes from Original (December 2014) to Revision A</b>	<b>Page</b>
• Updated $t_{d(on)}$ value in the <a href="#">Electrical Characteristics</a> table. ....	<b>3</b>
• Updated $t_r$ value in the <a href="#">Electrical Characteristics</a> table. ....	<b>3</b>
• Updated $t_{d(off)}$ value in the <a href="#">Electrical Characteristics</a> table. ....	<b>3</b>
• Updated $t_f$ value in the <a href="#">Electrical Characteristics</a> table. ....	<b>3</b>
• Added <a href="#">Community Resources</a> section. ....	<b>7</b>

## 5 Specifications

### 5.1 Electrical Characteristics

(T<sub>A</sub> = 25°C unless otherwise stated)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT	
STATIC CHARACTERISTICS							
BV <sub>DSS</sub>	Drain-to-source voltage	V <sub>GS</sub> = 0 V, I <sub>DS</sub> = 250 μA	12			V	
I <sub>DSS</sub>	Drain-to-source leakage current	V <sub>GS</sub> = 0 V, V <sub>DS</sub> = 9.6 V	1			μA	
I <sub>GSS</sub>	Gate-to-source leakage current	V <sub>DS</sub> = 0 V, V <sub>GS</sub> = 10 V	10			μA	
V <sub>GS(th)</sub>	Gate-to-source threshold voltage	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>DS</sub> = 250 μA	0.70	1.00	1.25	V	
R <sub>DS(on)</sub>	Drain-to-source on-resistance	V <sub>GS</sub> = 2.5 V, I <sub>DS</sub> =0.5 A	53			65	mΩ
		V <sub>GS</sub> = 4.5 V, I <sub>DS</sub> =0.5 A	37			44	mΩ
g <sub>fs</sub>	Transconductance	V <sub>DS</sub> = 6 V, I <sub>DS</sub> = 0.5 A	5.4			S	
DYNAMIC CHARACTERISTICS							
C <sub>iss</sub>	Input capacitance	V <sub>GS</sub> = 0 V, V <sub>DS</sub> = 6 V, f = 1 MHz	224			291	pF
C <sub>oss</sub>	Output capacitance		68			88	pF
C <sub>rss</sub>	Reverse transfer capacitance		47			61	pF
R <sub>G</sub>	Series gate resistance		240				Ω
Q <sub>g</sub>	Gate charge total (4.5 V)	V <sub>DS</sub> = 6 V, I <sub>DS</sub> = 0.5 A	2.0			2.6	nC
Q <sub>gd</sub>	Gate charge gate-to-drain		0.6				nC
Q <sub>gs</sub>	Gate charge gate-to-source		0.4				nC
Q <sub>g(th)</sub>	Gate charge at V <sub>th</sub>		0.1				nC
Q <sub>oss</sub>	Output charge	V <sub>DS</sub> = 6 V, V <sub>GS</sub> = 0 V	0.9				nC
t <sub>d(on)</sub>	Turn on delay time	V <sub>DS</sub> = 6 V, V <sub>GS</sub> = 4.5 V, I <sub>DS</sub> = 0.5 A, R <sub>G</sub> = 2 Ω	46				ns
t <sub>r</sub>	Rise time		122				ns
t <sub>d(off)</sub>	Turn off delay time		250				ns
t <sub>f</sub>	Fall time		290				ns
DIODE CHARACTERISTICS							
V <sub>SD</sub>	Diode forward voltage	I <sub>SD</sub> = 0.5 A, V <sub>GS</sub> = 0 V	0.7			1.0	V

### 5.2 Thermal Information

(T<sub>A</sub> = 25°C unless otherwise stated)

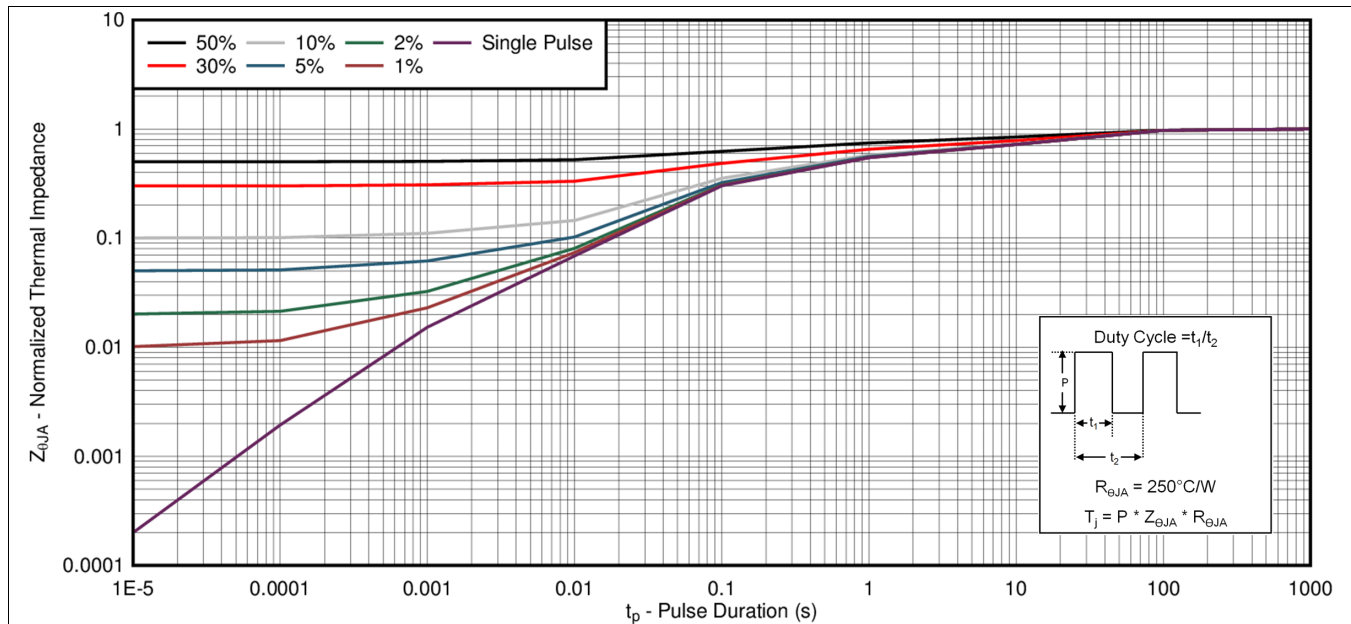
THERMAL METRIC		MIN	TYP	MAX	UNIT
R <sub>θJA</sub>	Junction-to-ambient thermal resistance <sup>(1)</sup>		90		°C/W
	Junction-to-ambient thermal resistance <sup>(2)</sup>		250		

(1) Device mounted on FR4 material with 1 inch<sup>2</sup> (6.45 cm<sup>2</sup>), 2 oz. (0.071 mm thick) Cu.

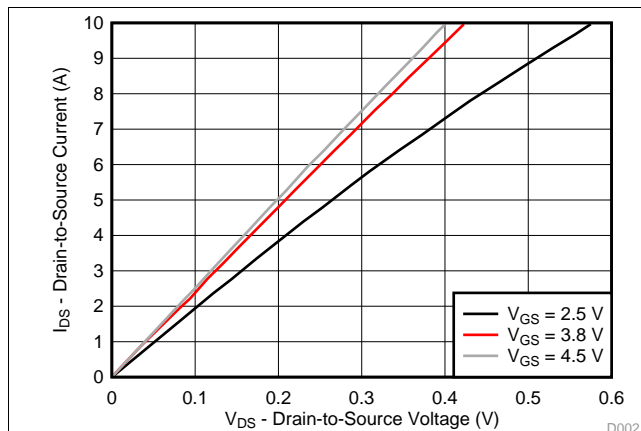
(2) Device mounted on FR4 material with minimum Cu mounting area.

### 5.3 Typical MOSFET Characteristics

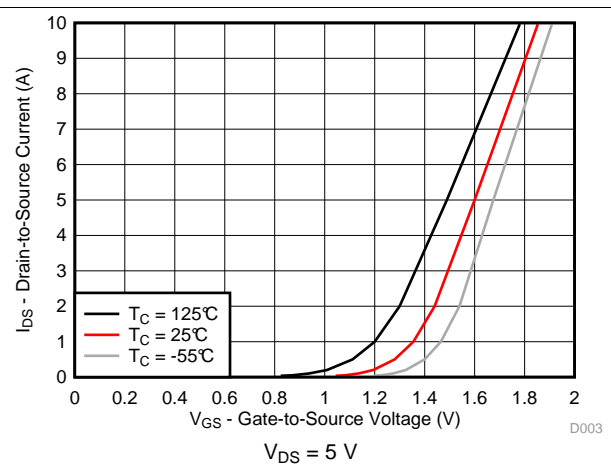
( $T_A = 25^\circ\text{C}$  unless otherwise stated)



**Figure 1. Transient Thermal Impedance**



**Figure 2. Saturation Characteristics**



**Figure 3. Transfer Characteristics**

## Typical MOSFET Characteristics (continued)

( $T_A = 25^\circ\text{C}$  unless otherwise stated)

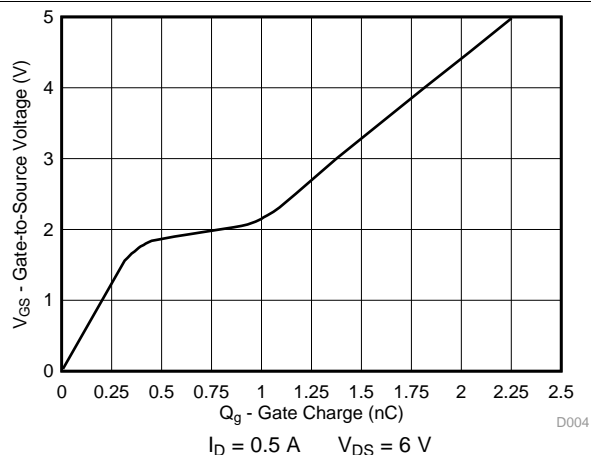


Figure 4. Gate Charge

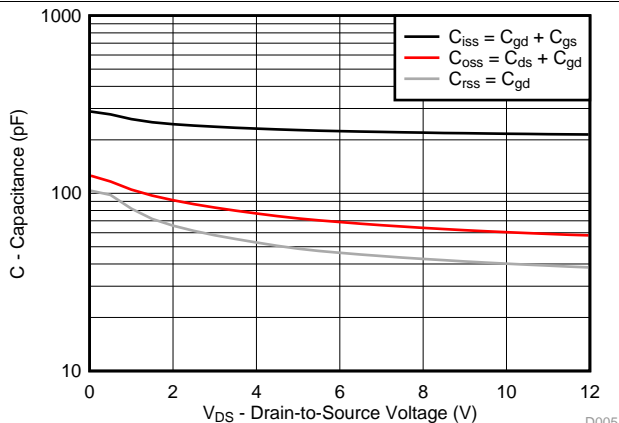


Figure 5. Capacitance

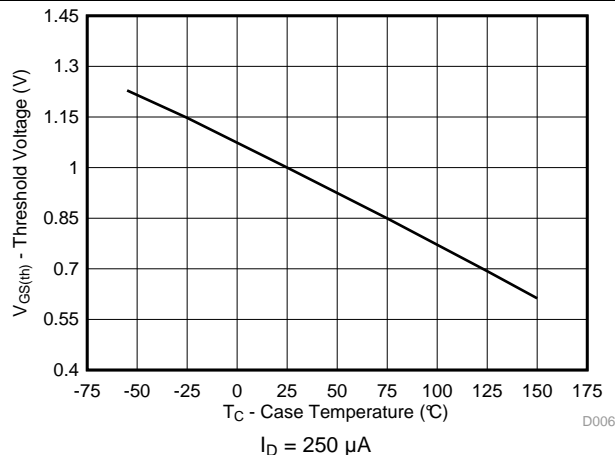


Figure 6. Threshold Voltage vs Temperature

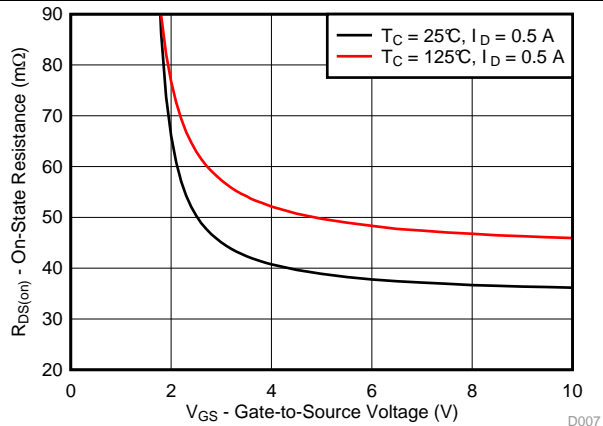


Figure 7. On-State Resistance vs Gate-to-Source Voltage

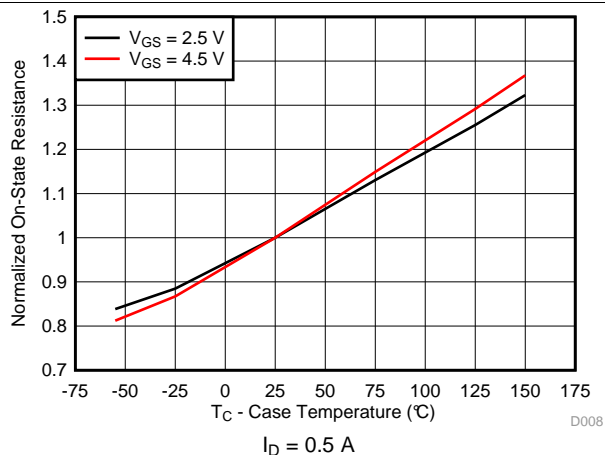


Figure 8. Normalized On-State Resistance vs Temperature

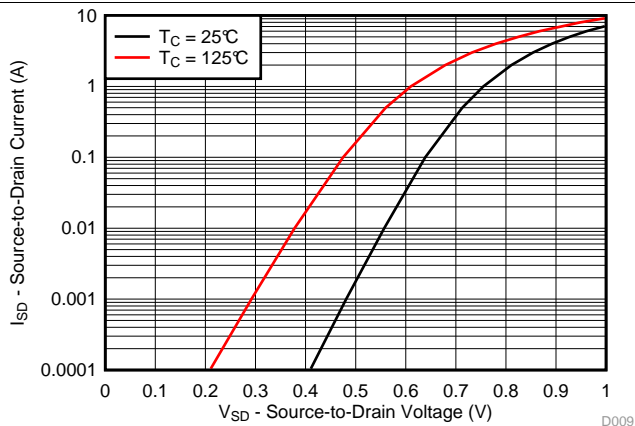
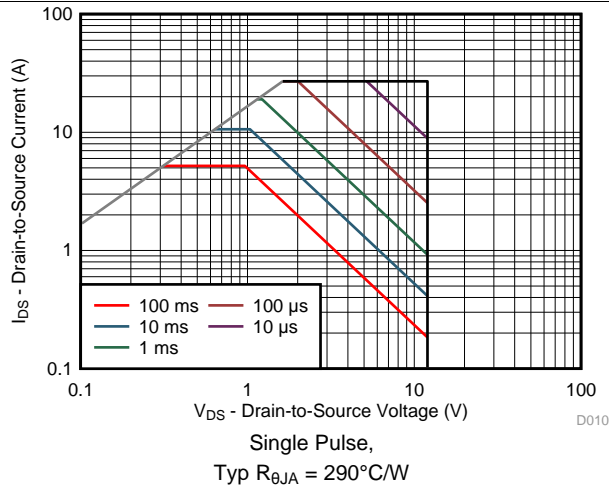


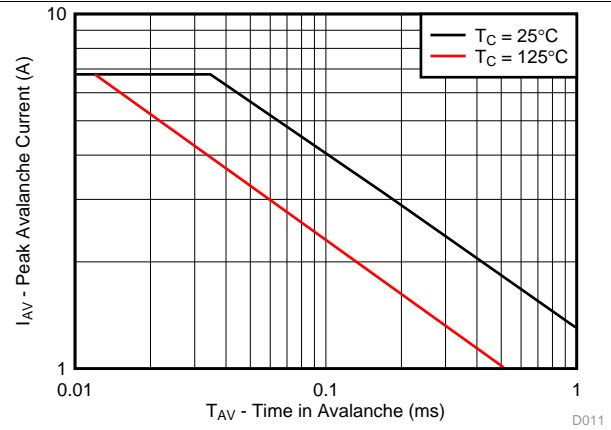
Figure 9. Typical Diode Forward Voltage

## Typical MOSFET Characteristics (continued)

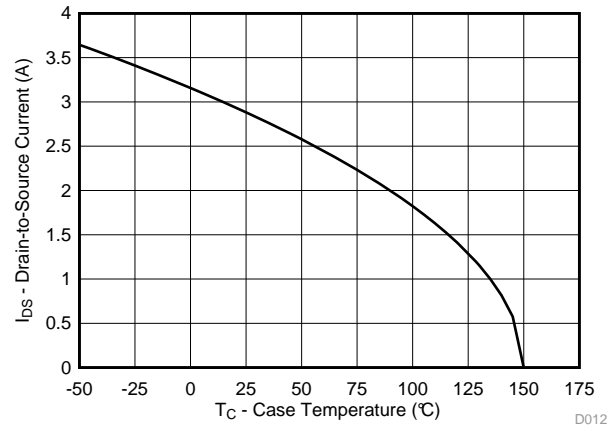
( $T_A = 25^\circ\text{C}$  unless otherwise stated)



**Figure 10. Maximum Safe Operating Area (SOA)**



**Figure 11. Single Pulse Unclamped Inductive Switching**



**Figure 12. Maximum Drain Current vs Temperature**

## 6 Device and Documentation Support

### 6.1 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

**TI E2E™ Online Community** *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At [e2e.ti.com](http://e2e.ti.com), you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support** *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

### 6.2 Trademarks

FemtoFET, E2E are trademarks of Texas Instruments.  
All other trademarks are the property of their respective owners.

### 6.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### 6.4 Glossary

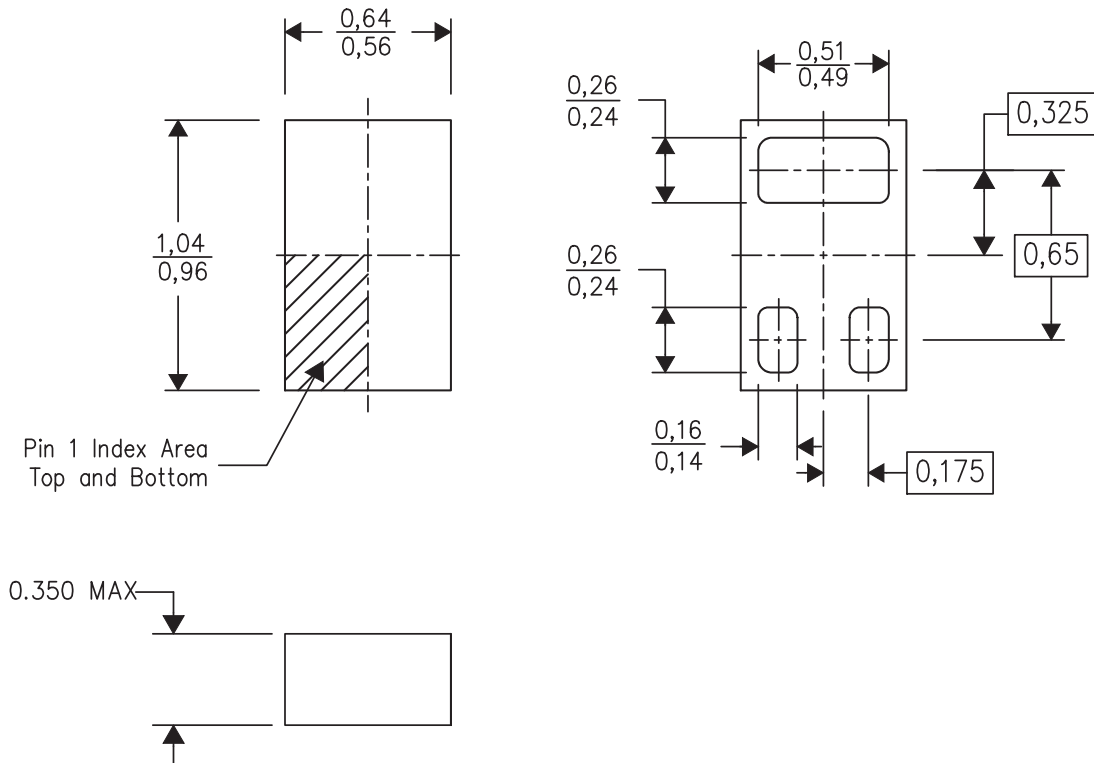
[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

## 7 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

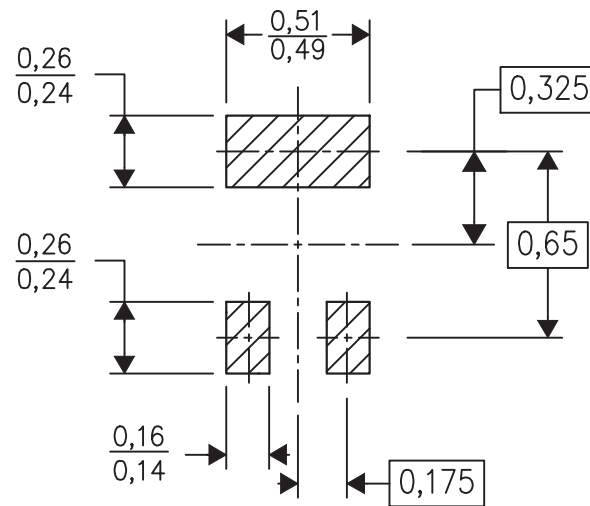
### 7.1 Mechanical Dimensions



- (1) All linear dimensions are in millimeters (dimensions and tolerancing per AME T14.5M-1994).
- (2) This drawing is subject to change without notice.
- (3) This package is a PB-free solder land design.

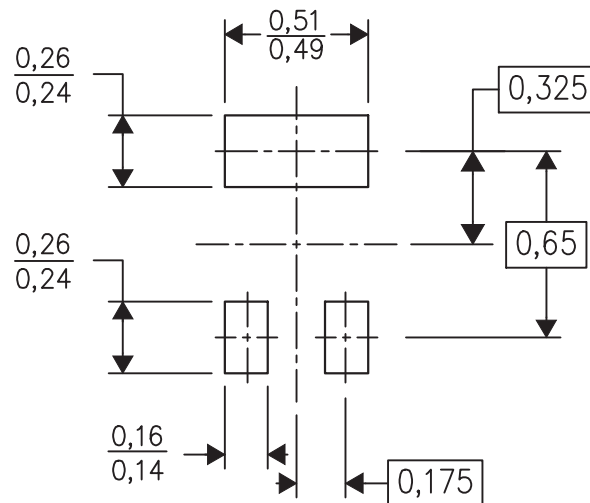


## 7.2 Recommended Minimum PCB Layout



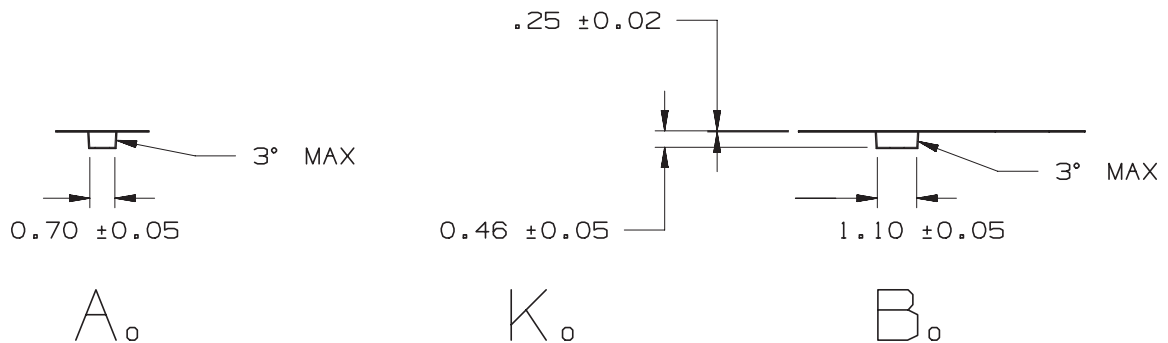
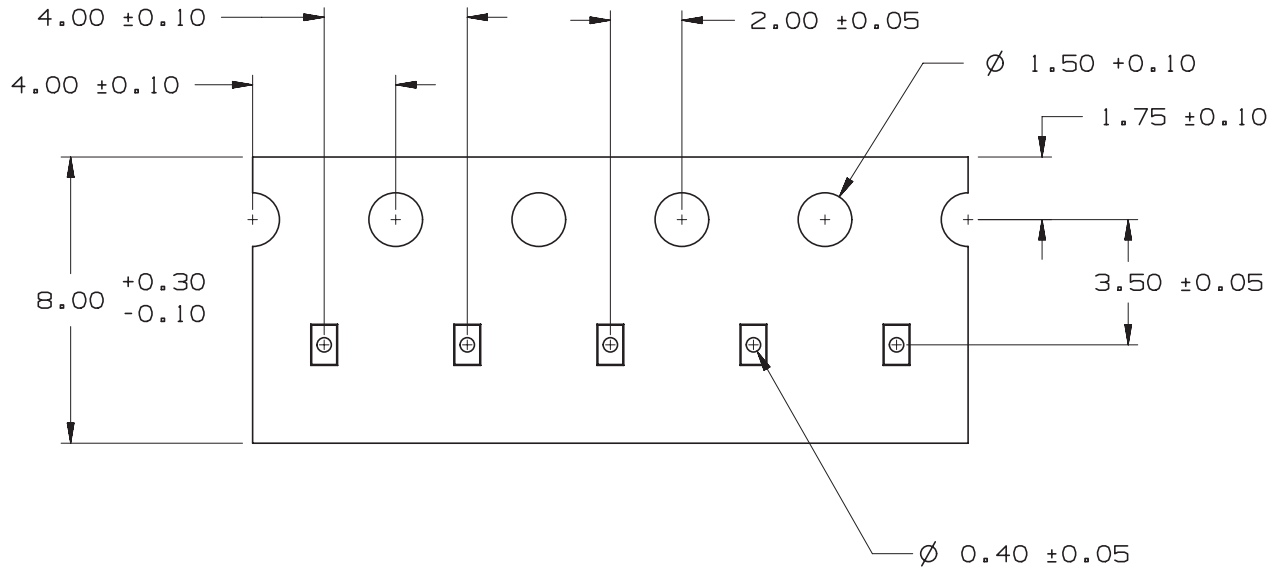
(1) All dimensions are in millimeters.

## 7.3 Recommended Stencil Pattern



(1) All dimensions are in millimeters.

## 7.4 CSD17381F4 Embossed Carrier Tape Dimensions



- (1) Pin 1 is oriented in the top-right quadrant of the tape enclosure (quadrant 2), closest to the carrier tape sprocket holes.

## PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
CSD13383F4	ACTIVE	PICOSTAR	YJC	3	3000	Green (RoHS & no Sb/Br)	Call TI	Level-1-260C-UNLIM		GC	<a href="#">Samples</a>
CSD13383F4T	ACTIVE	PICOSTAR	YJC	3	250	Green (RoHS & no Sb/Br)	Call TI	Level-1-260C-UNLIM		GC	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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### Products

Audio	<a href="http://www.ti.com/audio">www.ti.com/audio</a>
Amplifiers	<a href="http://amplifier.ti.com">amplifier.ti.com</a>
Data Converters	<a href="http://dataconverter.ti.com">dataconverter.ti.com</a>
DLP® Products	<a href="http://www.dlp.com">www.dlp.com</a>
DSP	<a href="http://dsp.ti.com">dsp.ti.com</a>
Clocks and Timers	<a href="http://www.ti.com/clocks">www.ti.com/clocks</a>
Interface	<a href="http://interface.ti.com">interface.ti.com</a>
Logic	<a href="http://logic.ti.com">logic.ti.com</a>
Power Mgmt	<a href="http://power.ti.com">power.ti.com</a>
Microcontrollers	<a href="http://microcontroller.ti.com">microcontroller.ti.com</a>
RFID	<a href="http://www.ti-rfid.com">www.ti-rfid.com</a>
OMAP Applications Processors	<a href="http://www.ti.com/omap">www.ti.com/omap</a>
Wireless Connectivity	<a href="http://www.ti.com/wirelessconnectivity">www.ti.com/wirelessconnectivity</a>

### Applications

Automotive and Transportation	<a href="http://www.ti.com/automotive">www.ti.com/automotive</a>
Communications and Telecom	<a href="http://www.ti.com/communications">www.ti.com/communications</a>
Computers and Peripherals	<a href="http://www.ti.com/computers">www.ti.com/computers</a>
Consumer Electronics	<a href="http://www.ti.com/consumer-apps">www.ti.com/consumer-apps</a>
Energy and Lighting	<a href="http://www.ti.com/energy">www.ti.com/energy</a>
Industrial	<a href="http://www.ti.com/industrial">www.ti.com/industrial</a>
Medical	<a href="http://www.ti.com/medical">www.ti.com/medical</a>
Security	<a href="http://www.ti.com/security">www.ti.com/security</a>
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